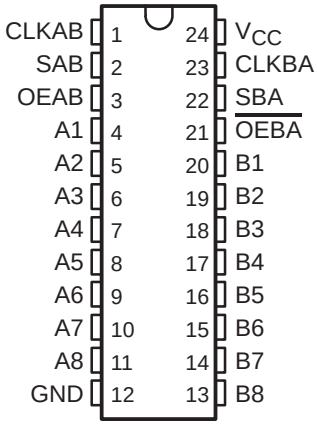
- **BiCMOS Technology With Low Quiescent Power**
- **Buffered Inputs**
- **Noninverted Outputs**
- **Input/Output Isolation From V_{CC}**
- **Controlled Output Edge Rates**
- **64-mA Output Sink Current**
- **Output Voltage Swing Limited to 3.7 V**
- **SCR Latch-Up-Resistant BiCMOS Process and Circuit Design**
- **Multiplexed Real-Time and Stored Data**
- **Package Options Include Plastic Small-Outline (M) Package and Standard Plastic (EN) DIP**

EN OR M PACKAGE
(TOP VIEW)



description

The CD74FCT652 is an octal bus transceiver and resistor with 3-state outputs. It consists of D-type flip-flops and control circuitry, arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output-enable (OEAB and $\overline{\text{OEBA}}$) inputs control the transceiver functions. The select-control (SAB and SBA) inputs select real-time-data or stored-data transfer. A low-input level selects real-time data, and a high-input level selects stored data. The select-control circuitry eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored data and real-time data.

The device uses a small-geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output high level to two diode drops below V_{CC}. This resultant lowering of output swing (0 V to 3.7 V) reduces power-bus ringing [a source of electromagnetic interference (EMI)] and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 mA.

Data on the A or B data bus, or both, can be stored in the internal D-type flip-flop by low-to-high transitions at the appropriate clock terminal (CLKAB and CLKBA), regardless of the state of the select or enable control terminals. When SAB and SBA are in the real-time-transfer mode, it also is possible to store data without using the internal D-type flip-flop by simultaneously enabling OEAB and $\overline{\text{OEBA}}$. In this configuration, each output reinforces its input. Thus, when all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last state.

To ensure the high-impedance state during power up or power down, $\overline{\text{OEBA}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver (B to A). OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver (A to B).

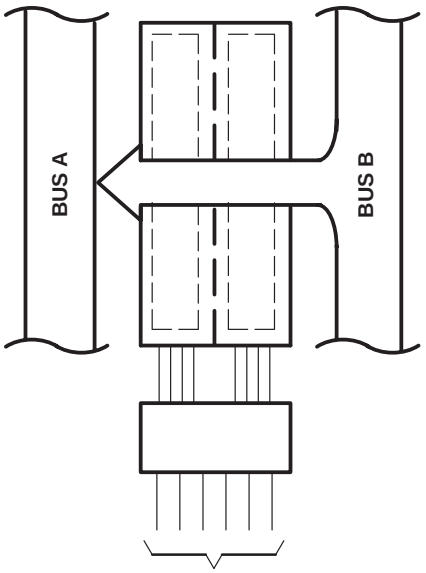
The CD74FCT652 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

INPUTS						DATA I/O		OPERATION OR FUNCTION
OEAB	$\overline{\text{OEBA}}$	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	
L	H	H or L	H or L	X	X	Input	Input	Isolation
L	H	↑	↑	X	X	Input	Input	Store A and B data
X	H	↑	H or L	X	X	Input	Unspecified†	Store A, hold B
H	H	↑	↑	X‡	X	Input	Output	Store A in both registers
L	X	H or L	↑	X	X	Unspecified†	Input	Hold A, store B
L	L	↑	↑	X	X‡	Output	Input	Store B in both registers
L	L	X	X	X	L	Output	Input	Real-time $\overline{\text{B}}$ data to A bus
L	L	X	H or L	X	H	Output	Input	Stored $\overline{\text{B}}$ data to A bus
H	H	X	X	L	X	Input	Output	Real-time $\overline{\text{A}}$ data to B bus
H	H	H or L	X	H	X	Input	Output	Stored $\overline{\text{A}}$ data to B bus
H	L	H or L	H or L	H	H	Output	Output	Stored $\overline{\text{A}}$ data to B bus and stored $\overline{\text{B}}$ data to A bus

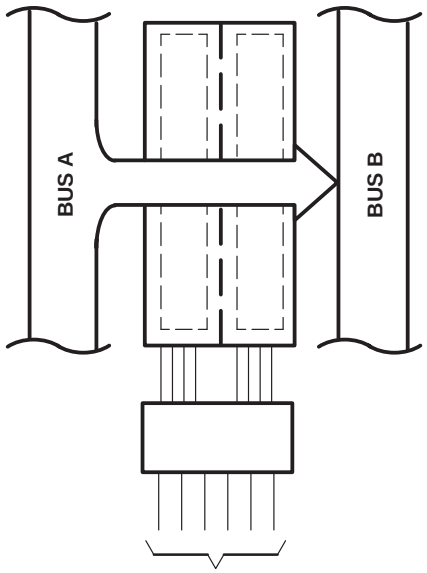
† The data output functions can be enabled or disabled by various level combinations at OEAB or $\overline{\text{OEBA}}$. Data input functions always are enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

‡ When select control is low, clocks can occur simultaneously if allowances are made for propagation delays from A to B (B to A) plus setup and hold times. When select control is high, clocks must be staggered to load both registers.



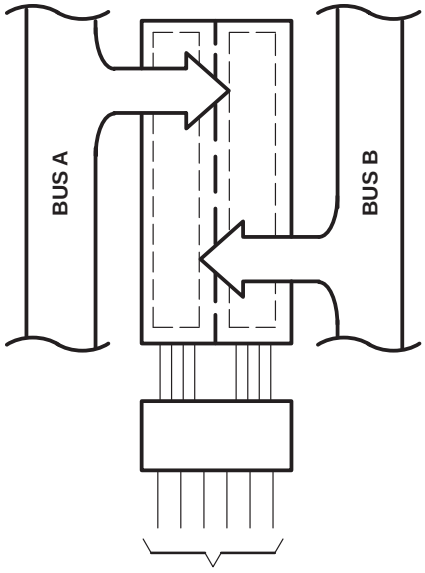
3	21	1	23	2	22
OEAB	$\overline{\text{OEBA}}$	CLKAB	CLKBA	SAB	SBA
L	L	X	X	X	L

REAL-TIME TRANSFER
BUS B TO BUS A



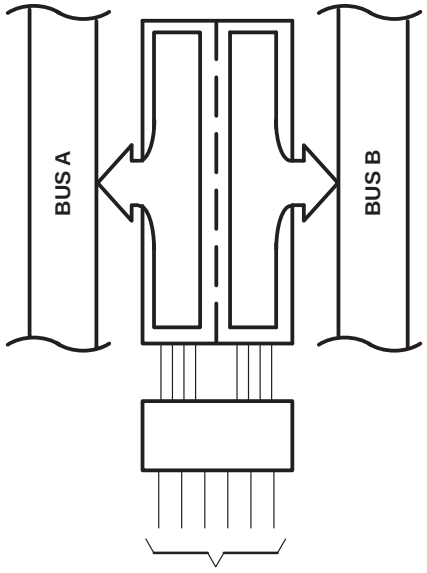
3	21	1	23	2	22
OEAB	$\overline{\text{OEBA}}$	CLKAB	CLKBA	SAB	SBA
H	H	X	X	L	X

REAL-TIME TRANSFER
BUS A TO BUS B



3	21	1	23	2	22
OEAB	$\overline{\text{OEBA}}$	CLKAB	CLKBA	SAB	SBA
X	H	↑	X	X	X
L	X	X	↑	X	X
L	H	↑	↑	X	X

STORAGE FROM A, B, OR A AND B

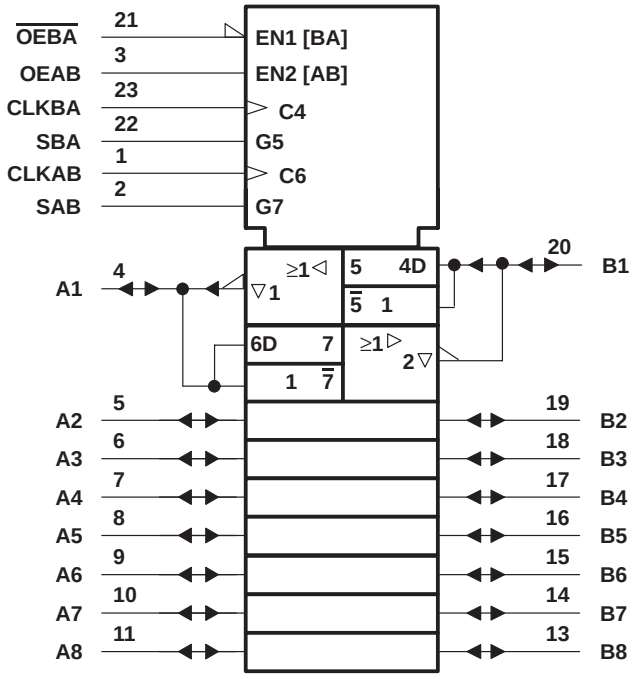


3	21	1	23	2	22
OEAB	$\overline{\text{OEBA}}$	CLKAB	CLKBA	SAB	SBA
H	L	H or L	H or L	H	H

TRANSFER STORED DATA TO A AND/OR B

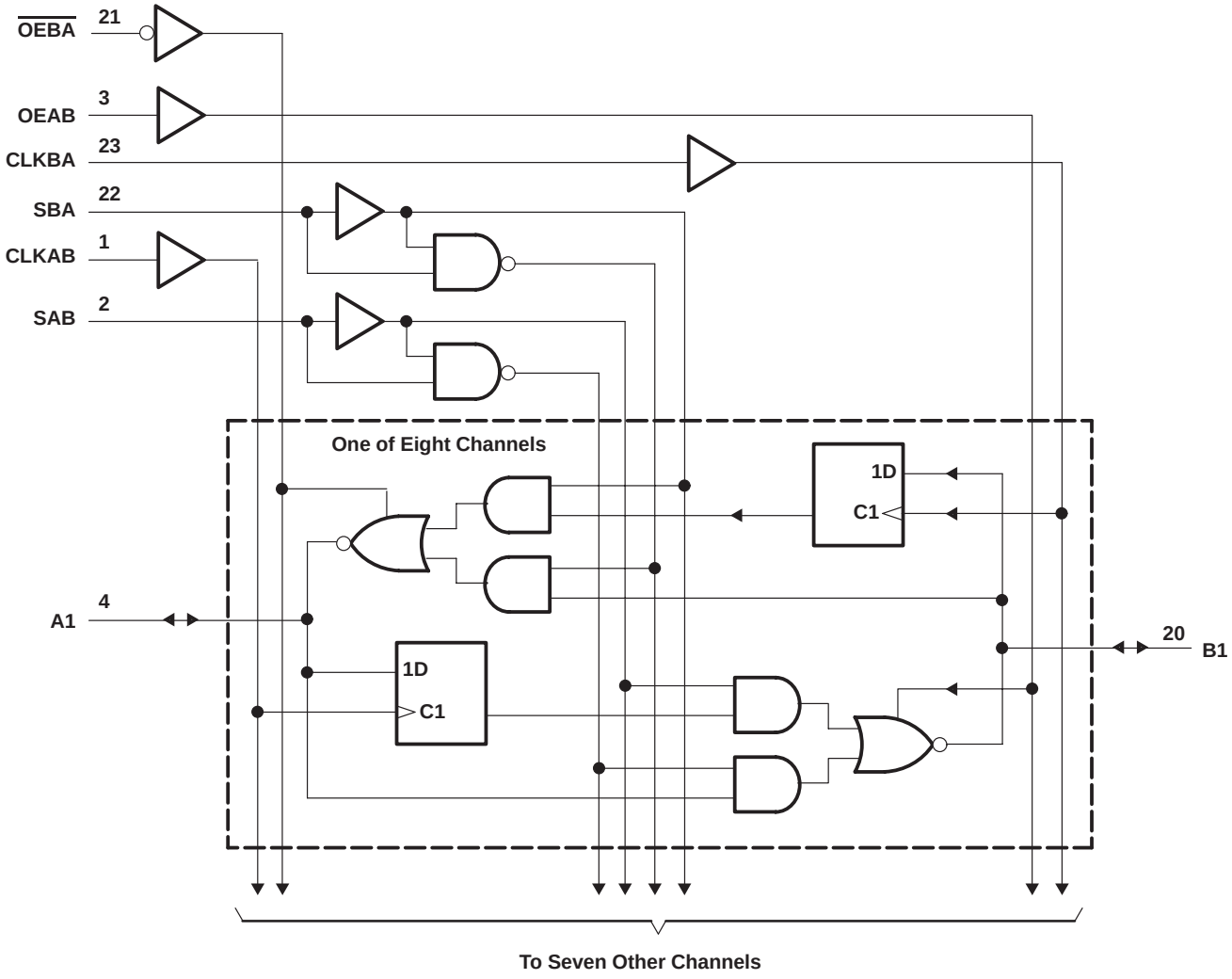
Figure 1. Bus-Management Functions

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

DC supply voltage range, V_{CC} . . . . . –0.5 V to 6 V
DC input clamp current, I_{IK} (V_I < –0.5 V) . . . . . –20 mA
DC output clamp current, I_{OK} (V_O < –0.5 V) . . . . . –50 mA
DC output sink current per output pin, I_{OL} . . . . . 70 mA
DC output source current per output pin, I_{OH} . . . . . –30 mA
Continuous current through V_{CC}, I_{CC} . . . . . 140 mA
Continuous current through GND . . . . . 528 mA
Package thermal impedance, θ_{JA} (see Note 1): EN package . . . . . 67°C/W
M package . . . . . 46°C/W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 2)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	4.75	5.25	V
V_{IH}	High-level input voltage	2		V
V_{IL}	Low-level input voltage		0.8	V
V_I	Input voltage	0	V_{CC}	V
V_O	Output voltage	0	V_{CC}	V
I_{OH}	High-level output current		–15	mA
I_{OL}	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
T_A	Operating free-air temperature	0	70	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V_{CC}	T_A = 25°C		MIN	MAX	UNIT
				MIN	MAX			
V_{IK}	I_I = –18 mA		4.75 V		–1.2		–1.2	V
V_{OH}	I_{OH} = –15 mA		4.75 V	2.4		2.4		V
V_{OL}	I_{OL} = 64 mA		4.75 V		0.55		0.55	V
I_I	$V_I = V_{CC}$ or GND		5.25 V		±0.1		±1	µA
I_{OZ}	$V_O = V_{CC}$ or GND		5.25 V		±0.5		±10	µA
I_{OS}‡	$V_I = V_{CC}$ or GND,	V_O = 0	5.25 V	–60		–60		mA
I_{CC}	$V_I = V_{CC}$ or GND,	I_O = 0	5.25 V		8		80	µA
ΔI_{CC}§	One input at 3.4 V, Other inputs at V_{CC} or GND		5.25 V		1.6		1.6	mA
C_i	$V_I = V_{CC}$ or GND				10		10	pF
C_o	$V_O = V_{CC}$ or GND				15		15	pF

‡ Not more than one output should be tested at a time, and the duration of the test should not exceed 100 ms.
§ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

timing requirements over recommended operating temperature conditions (unless otherwise noted) (see Figure 2)

			MIN	MAX	UNIT
f_{clock}	Clock frequency			85	MHz
t_w	Pulse duration	CLK high or low	6		ns
t_{su}	Setup time	A before CLKAB↑ or B before CLKBA↑	4		ns
t_h	Hold time	A after CLKAB↑ or B after CLKBA↑	2		ns

switching characteristics over recommended operating temperature conditions (unless otherwise noted) (see Figure 2)

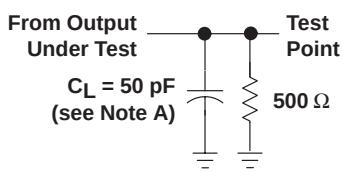
PARAMETER	FROM (INPUT)	TO (OUTPUT)	T_A = 25°C TYP	MIN	MAX	UNIT
f_{max}				85		MHz
t_{pd}	A or B	B or A	6.8	2	9	ns
	CLKBA or CLKAB	A or B	6.8	2	9	
	SBA or SAB†	A or B	8.3	2	11	
t_{en}	$\overline{OE}$	A or B	7.5	2	10	ns
t_{dis}	$\overline{OE}$	A or B	7.5	2	10	ns

† These parameters are measured with the internal output state of the storage register opposite that of the bus input.

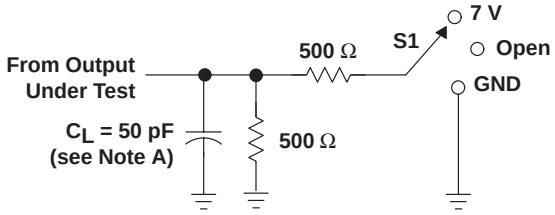
noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C

PARAMETER		MIN	TYP	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		1		V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		0.5		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

PARAMETER MEASUREMENT INFORMATION

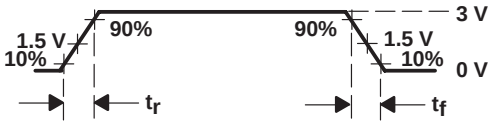


LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

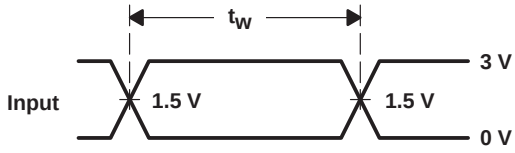


LOAD CIRCUIT FOR
3-STATE AND OPEN-DRAIN OUTPUTS

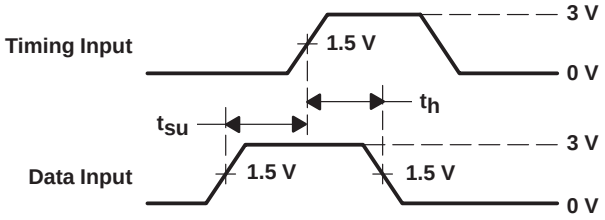
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open
Open Drain	7 V



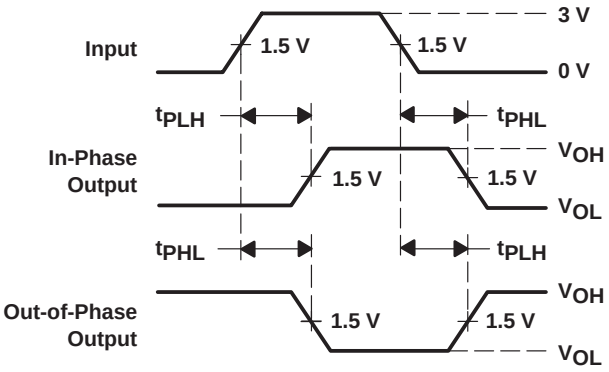
VOLTAGE WAVEFORM
INPUT RISE AND FALL TIMES



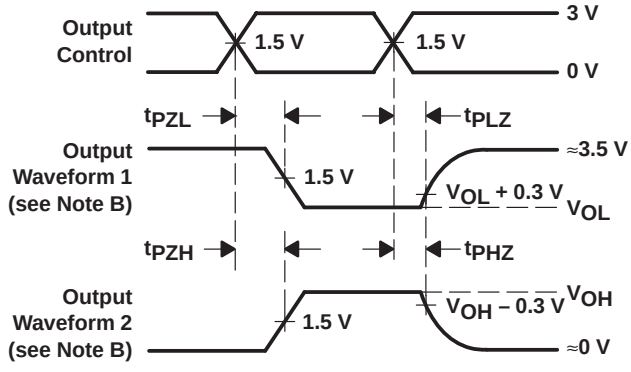
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r and t_f = 2.5 ns.
D. The outputs are measured one at a time with one input transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. t_{PHL} and t_{PLH} are the same as t_{pd}.

Figure 2. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
CD74FCT652EN	OBSOLETE	PDIP	NT	24		TBD	Call TI	Call TI
CD74FCT652M	OBSOLETE	SOIC	DW	24		TBD	Call TI	Call TI

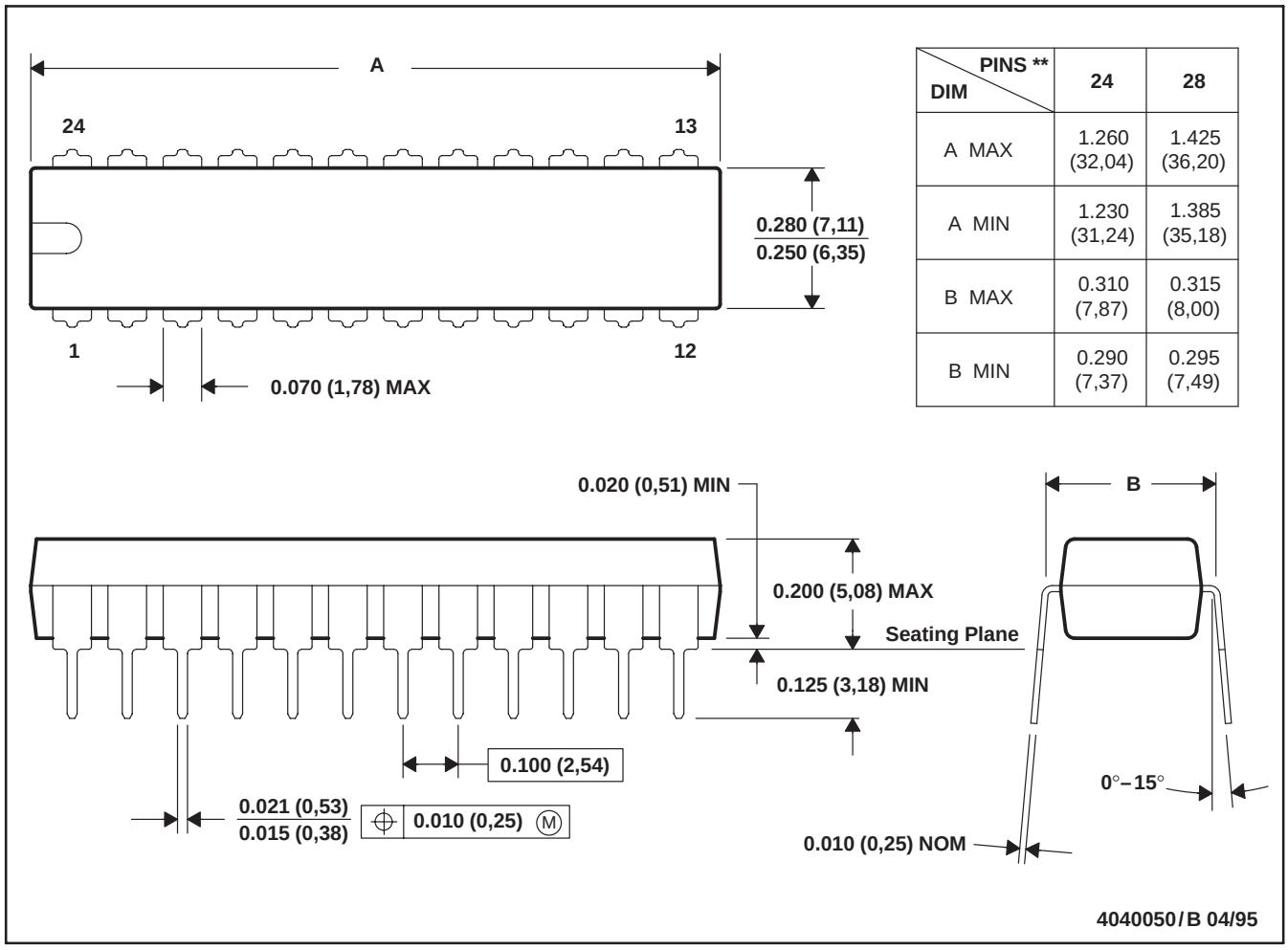
(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

NT (R-PDIP-T)** **PLASTIC DUAL-IN-LINE PACKAGE**

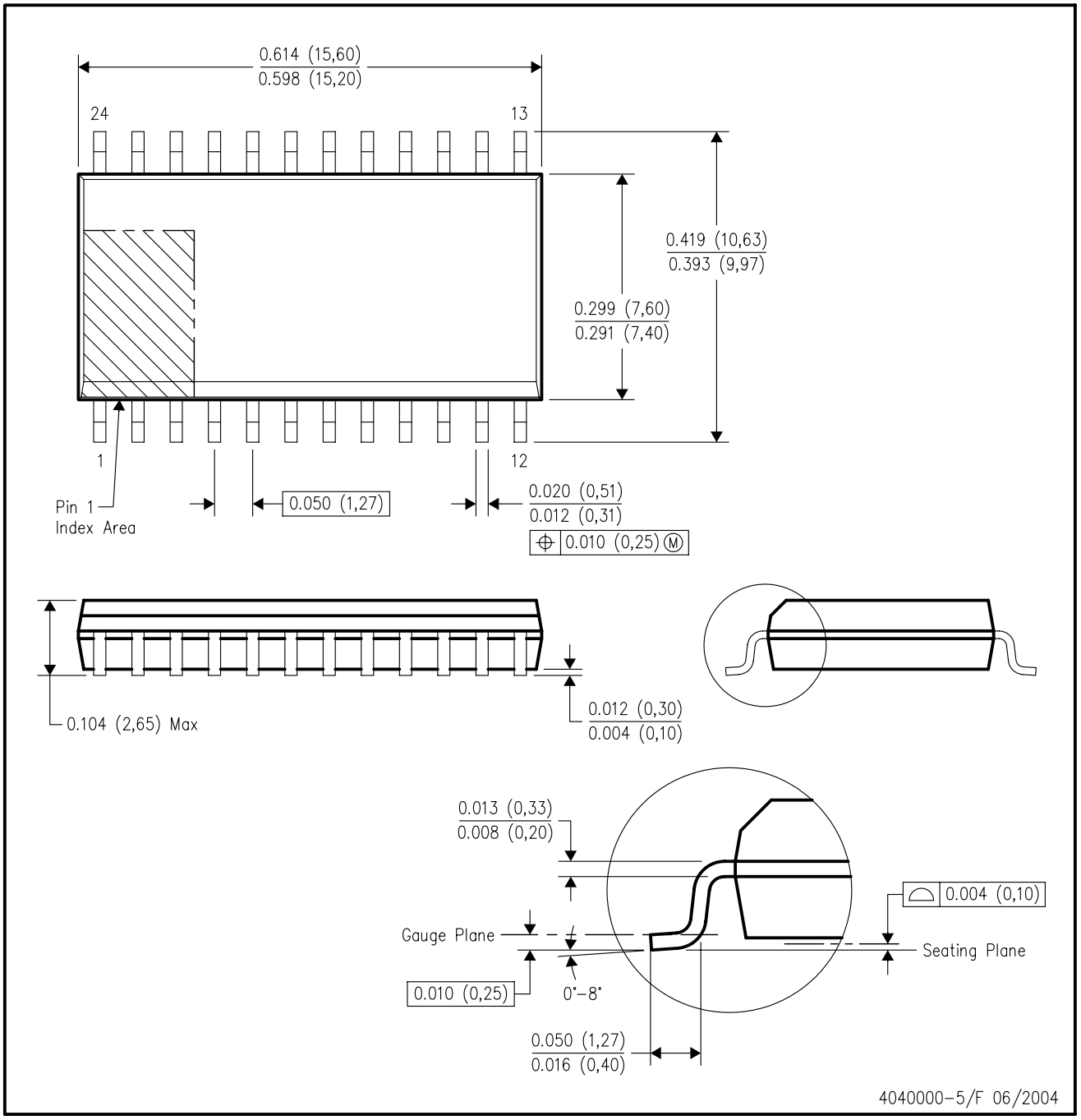
24 PINS SHOWN



DIM \ PINS **	24	28
A MAX	1.260 (32,04)	1.425 (36,20)
A MIN	1.230 (31,24)	1.385 (35,18)
B MAX	0.310 (7,87)	0.315 (8,00)
B MIN	0.290 (7,37)	0.295 (7,49)

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.

DW (R–PDSO–G24) PLASTIC SMALL–OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS–013 variation AD.

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